

INCHANGE SEMICONDUCTOR

isc Silicon NPN Power Transistor

2SC5339

DESCRIPTION

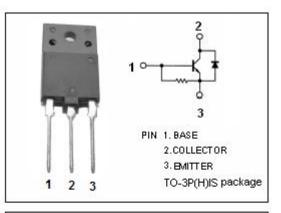
- · High Breakdown Voltage-
 - : V_{CBO}= 1500V (Min)
- · High Switching Speed
- Low Saturation Voltage
- Built-in Damper Diode
- 100% avalanche tested
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation

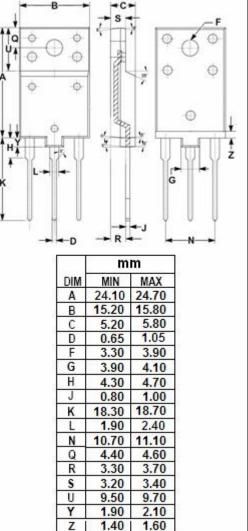
APPLICATIONS

· Horizontal output applications for medium resolution display & color TV.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)				
SYMBOL	PARAMETER	VALUE	UNIT	
V _{CBO}	Collector-Base Voltage	1500	V	
V _{CEO}	Collector-Emitter Voltage	600	V	
V_{EBO}	Emitter-Base Voltage	5	V	
lc	Collector Current- Continuous	7	А	
I _{СМ}	Collector Current- Continuous	14	A	
I _B	Base Current- Continuous	3.5	A	
Pc	Collector Power Dissipation @ T_C =25°C	50	W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	







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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 400mA; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 5A; I _B = 1.25A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 5A; I _B = 1.25A			1.3	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 1500V; I _E = 0			1.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			250	mA
h _{FE-1}	DC Current Gain	I _C = 1A; V _{CE} = 5V	8		20	
h _{FE-2}	DC Current Gain	I _C = 5A; V _{CE} = 5V	4		8	
V _{ECF}	C-E Diode Forward Voltage	I _F = 5A			1.8	V
f⊤	Current-Gain—Bandwidth Product	I _C = 0.1A; V _{CE} = 10V		24		MHz
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} =1.0MHz		82		pF

Switching Times

t _{stg}	Storage Time	I _{CP} = 5A; I _{B1} = 1.1A R _L = 39 Ω		6.0	μ \$
t _f	Fall Time			0.5	μ \$



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